

## United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/606,823	06/26/2003	Shih-Ming Chang	67,200-1010	5507	
75	90 08/12/2005		EXAMINER		
TUNG & ASSOCIATES			GARCIA, JOANNIE A		
Suite 120 838 W. Long La	ake Road		ART UNIT	PAPER NUMBER	
Bloomfield Hill			2823	2823	
				DATE MAILED: 08/12/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

			DI				
	Application No.	Applicant(s)					
	10/606,823	CHANG ET AL.					
Office Action Summary	Examiner	Art Unit					
	Joannie A. García	2823					
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the	correspondence addre	2SS				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a repl If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be till by within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a, cause the application to become ABANDONE	mely filed ys will be considered timely. n the mailing date of this comn ED (35 U.S.C. § 133).	nunication.				
Status							
1) Responsive to communication(s) filed on 22 J	ulv 2005.						
	s action is non-final.						
3) Since this application is in condition for allowa							
Disposition of Claims							
4) ☐ Claim(s) 24-38 is/are pending in the application 4a) Of the above claim(s) is/are withdra  5) ☐ Claim(s) is/are allowed.  6) ☐ Claim(s) 24-38 is/are rejected.  7) ☐ Claim(s) is/are objected to.  8) ☐ Claim(s) are subject to restriction and/or	wn from consideration.						
Application Papers							
9)☐ The specification is objected to by the Examine	er.						
10) ☐ The drawing(s) filed on is/are: a) ☐ acc							
Applicant may not request that any objection to the							
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the E							
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureat * See the attached detailed Office action for a list	ts have been received. ts have been received in Applicat prity documents have been receiv uu (PCT Rule 17.2(a)).	tion No red in this National St	age				
Attachment(s)	_						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summar Paper No(s)/Mail D						
<ul> <li>2) Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)</li> <li>Paper No(s)/Mail Date</li> </ul>		Patent Application (PTO-1	52)				

The finality stated in the office action mailed 03-22-05, has been withdrawn.

Claims 29, and 31-38, are objected to because of the following informalities:

Appropriate correction is required.

In claims 29 and 30, lines 4 and 6, respectively, "a" before "layout for the", should be replaced with --another--.

In claim 31, lines 2 and 6, "first mask part" should be followed by --that--.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 24-38 are rejected under 35 U.S.C. 102(b) as being anticipated by Higashikawa et al (U.S. Patent 6,319,637).

Higashikawa et al discloses a lithographic semiconductor fabrication process comprising exposing a semiconductor wafer to a first mask part that comprises a layout for a semiconductor device that is at least defective (Figure 2A, and Column 7, lines 7-10), exposing the semiconductor wafer to a second mask part corresponding to the first mask part that comprises another layout for the semiconductor device that is at least free from defects, a second and a third time (Figures 2A-2C, and Column 7, lines 35-67), wherein the first and second mask parts are formed on a same photomask (Figure 2A), and wherein said first mask part and said second mask part are on different photomasks (Figures 2C-2D, and 3A-3B, Column 5, lines 7-8, and

Art Unit: 2823

Column 7, lines 35-67), exposing the semiconductor wafer to a third mask part one or more times (Figures 2A-2E), exposing the semiconductor wafer to the second mask part a second and a third time, or one or more times (Column 7, lines 45-67), and exposing the semiconductor wafer to the second, a third and other additional mask parts one or more additional times (Figures 2A-2E, and Column 7, lines 21-67).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Joannie García whose telephone number is (571) 272-1861. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith, can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

George Fourson Primary Examiner Art Unit 2823

JAG

August 8, 2005

GFourson

Primary Examiner